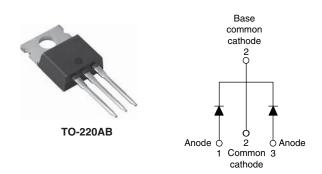
**Vishay Semiconductors** 

## High Performance Schottky Rectifier, 2 x 30 A



www.vishay.com

PRODUCT SUMMARY						
Package	TO-220AB					
I <sub>F(AV)</sub>	2 x 30 A					
V <sub>R</sub>	150 V					
V <sub>F</sub> at I <sub>F</sub>	0.72 V					
I <sub>RM</sub> max.	20 mA at 125 °C					
T <sub>J</sub> max.	175 °C					
Diode variation	Common cathode					
E <sub>AS</sub>	0.4 mJ					

#### FEATURES

- 175 °C T<sub>J</sub> operation
- Low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance



COMPLIANT

HALOGEN

FREE

- Guard-ring for enhanced ruggedness and long term reliability
- AEC-Q101 qualified, meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### DESCRIPTION

The center tap Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL CHARACTERISTICS VALUES U							
I <sub>F(AV)</sub>	Rectangular waveform	60	А				
V <sub>RRM</sub>		150	V				
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	710	А				
V <sub>F</sub>	30 $A_{pk}$ , $T_J$ = 125 °C (typical, per leg)	0.69	V				
TJ	Range	-55 to +175	°C				

VOLTAGE RATINGS						
PARAMETER SYMBOL VS-60CTQ150HN3 UNITS						
Maximum DC reverse voltage	V <sub>R</sub>	150	N/			
Maximum working peak reverse voltage	V <sub>RWM</sub>	150	v			

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST COND	TEST CONDITIONS					
Maximum average forward per leg				30				
current, see fig. 5 per device	$I_{F(AV)}$ 50 % duty cycle at T <sub>C</sub> = 137 °C, rectangular waveform		60	<u>^</u>				
Maximum peak one cycle non-repetitive		5 μs sine or 3 μs rect. pulse Following any rated load condition and with rated		710	A			
surge current per leg, see fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	V <sub>RRM</sub> applied	270				
Non-repetitive avalanche energy per leg		T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 0.9 A, L = 1 mH		0.4	mJ			
Repetitive avalanche current per leg		Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical		0.9	А			

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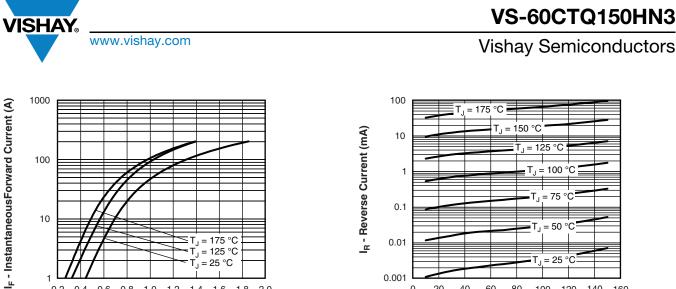
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ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS TYP MA					
		30 A	T.I = 25 °C	0.83	0.88			
Maximum forward voltage drop per leg	V <sub>FM</sub> <sup>(1)</sup>	60 A	1j=25 0	0.98	1.09	V		
See fig. 1	VFM (*)	30 A	T.I = 125 °C	0.67	0.72			
		60 A	1j = 125 C	0.82	0.87			
Maximum reverse leakage current per leg	I <sub>RM</sub>	T <sub>J</sub> = 25 °C	$V_{\rm B} = \text{Rated } V_{\rm B}$	7	75	μA		
See fig. 2		T <sub>J</sub> = 125 °C	VR - naleu VR	7.2	20	mA		
Typical junction capacitance per leg	CT	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz		-	650	pF		
Typical series inductance per leg	L <sub>S</sub>	Measured lead to lead 5 mm from package body			7.5	nH		
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub> - 10 000				V/µs		

#### Note

 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction and storage temperature range	)	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C		
Maximum thermal resistance,	per leg	D	DC operation, see fig. 4	1.2			
junction to case per package		R <sub>thJC</sub>	DC operation	0.6	°C/W		
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth and greased	0.25	0,11		
Approvimate weight				6	g		
Approximate weight				0.21	oz.		
Mounting torque				6 (5)	kgf ⋅ cm		
Mounting torque	maximum			12 (10)	$(lbf \cdot in)$		
Marking device			Case style TO-220AB	60CTC	Q150H		



# I<sub>R</sub> - Reverse Current (mA) 0.1 T<sub>.1</sub> = 175 °C

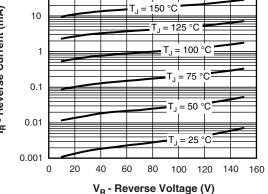


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

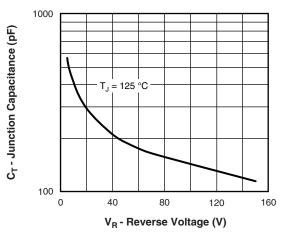


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

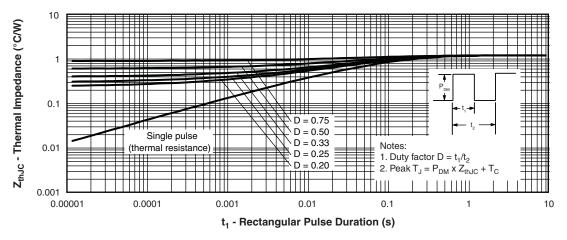


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics (Per Leg)

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V<sub>FM</sub> - Forward Voltage Drop (V) Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

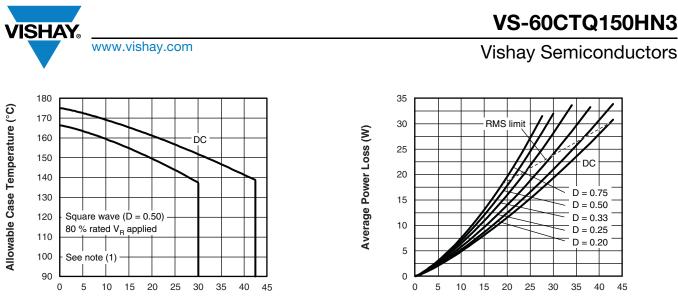
= 125 °C = 25 °C

1.4 1.6 1.8 2.0

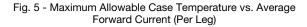
10

0.2 0.4

0.6 0.8 1.0 1.2



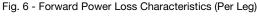
I<sub>F(AV)</sub> - Average Forward Current (A)

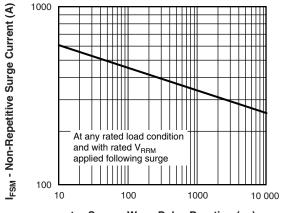


I<sub>F(AV)</sub> - Average Forward Current (A)

DC

40 45





tp - Square Wave Pulse Duration (µs)

Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

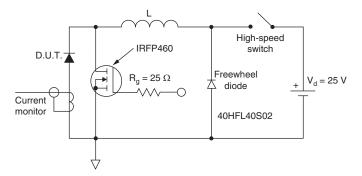


Fig. 8 - Unclamped Inductive Test Circuit

#### Note

Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ; (1)

 $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$ 

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#### **ORDERING INFORMATION TABLE**

Device code	VS-	60	С	т	Q	150	Н	N3	
	(1)	(2)	(3)	(4)	(5)	(6)	(7)	(8)	
1 2	-	Curren	t rating	nductor (60 = 60	•	ct	0	0	
3	-	Circuit configuration C = common cathode Package							
5	-		(y "Q" se		50 V)				
7	-	H = AE	Voltage rating (150 = 150 V) H = AEC-Q101 qualified Environmental digit						
				free, Ro	HS-com	pliant, a	and tota	lly lead	

ORDERING INFORMATION (Example)							
PREFERRED P/N QUANTITY PER T/R MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION							
VS-60CTQ150HN3	50	1000	Antistatic plastic tube				

LINKS TO RELATED DOCUMENTS					
Dimensions www.vishay.com/doc?95222					
Part marking information	www.vishay.com/doc?95028				



**Vishay Semiconductors** 

**TO-220AB** 

#### **DIMENSIONS** in millimeters and inches





.ead	assignments

**Diodes** 

1. - Anode/open 2. - Cathode 3. - Anode

SYMBOL	MILLIN	IETERS	INC	NOTES	
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6

#### Notes

- <sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994
- <sup>(2)</sup> Lead dimension and finish uncontrolled in L1
- <sup>(3)</sup> Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- $^{\left( 4\right) }$  Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1

MILLIMETERS INCHES SYMBOL NOTES MIN. MAX. MIN. MAX. 10.51 0.414 10.11 0.398 3,6 Е E1 6.86 8.89 0.270 0.350 6 E2 0.76 0.030 7 --2.41 2.67 0.095 0.105 е 0.208 e1 4.88 5.28 0.192 H1 6.09 6.48 0.240 0.255 6,7 13.52 14.02 0.532 0.552 L L1 3.32 3.82 0.131 0.150 2 ØΡ 3.54 3.73 0.139 0.147 2.60 0.102 Q 3.00 0.118 90° to 93° 90° to 93° θ

Conforms to JEDEC outline TO-220AB

- (7) Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline



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